

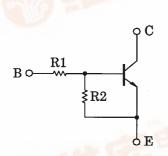
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN1601,RN1602,RN1603 RN1604,RN1605,RN1606

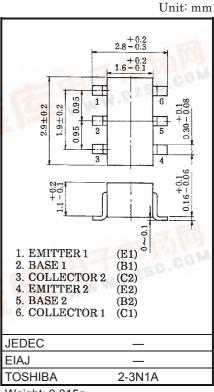
Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- Including two devices in SM6 (super mini type with 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2601~RN2606

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1601	4.7	4.7
RN1602	10	10
RN1603	22	22
RN1604	47	47
RN1605	2.2	47
RN1606	4.7	47

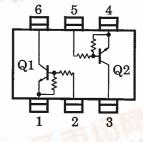


Weight: 0.015g

Equivalent Circuit (Top View)

Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic		Symbol	Rating	Unit	
Collector-base voltage	- RN1601~1606	V_{CBO}	50	V	
Collector-emitter voltage	- KN1001**1000	V _{CEO}	50	V	
Emitter-base voltage	RN1601~1604	V _{FBO}	10	V	
Emilier-base voltage	RN1605, 1606	, FBO	5		
Collector current		Ic	100	mA	
Collector power dissipation	- RN1601~1606	P _C *	300	mW	
Junction temperature	- KIN1001~1000	Tj	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	
* Total rating	9-11	COM			
	WWW.DZSG				



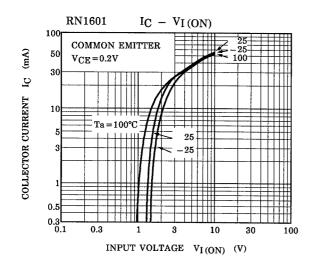


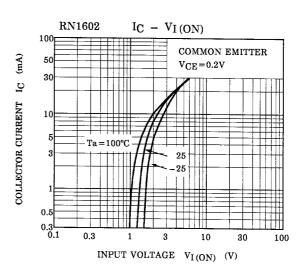
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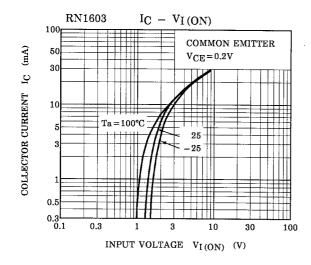
Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

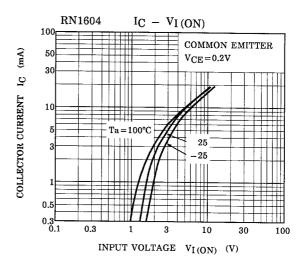
Characteri	stic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1601~1606	I _{CBO}	_	V _{CB} = 50V, I _E = 0	_	_	100	- nA
	KN 1001 1000	I _{CEO}	_	V _{CE} = 50V, I _B = 0	_	_	500	
	RN1601	I _{EBO}	_	V _{EB} = 10V, I _C = 0	0.82	_	1.52	mA
	RN1602		_		0.38	_	0.71	
Emitter cut-off current	RN1603		_		0.17	_	0.33	
	RN1604		_		0.082	_	0.15	
	RN1605		_	V _{EB} = 5V, I _C = 0	0.078	_	0.145	
	RN1606		_		0.074	_	0.138	
	RN1601		_		30	_	_	
	RN1602		_		50	_	_	
DC surrent main	RN1603	L	_)/ - 5\/ - 40mA	70	_	_	
DC current gain	RN1604	- h _{FE}	_	V_{CE} = 5V, I_{C} = 10mA	80	_	_	_
	RN1605		_		80	_	_	
	RN1606		_		80	_	_	
Collector-emitter saturation voltage	RN1601~1606	V _{CE (sat)}	_	I _C = 5mA, I _B = 0.25mA	_	0.1	0.3	٧
Input voltage (ON)	RN1601	V _I (ON)	_	V _{CE} = 0.2V, I _C = 5mA	1.1	_	2.0	V
	RN1602		_		1.2	_	2.4	
	RN1603		_		1.3	_	3.0	
	RN1604		_		1.5	_	5.0	
	RN1605		_		0.6	_	1.1	
	RN1606		_		0.7	_	1.3	
Input voltage (OFF)	RN1601~1604	V _{I (OFF)}	_	- V _{CE} = 5V, I _C = 0.1mA	1.0	_	1.5	V
	RN1605~1606		_		0.5	_	0.8	
Translation frequency	RN1601~1606	f _T	_	V _{CE} = 10V, I _C = 5mA	_	250	_	MHz
Collector output capacitance	RN1601~1606	C _{ob}	_	V _{CB} = 10V, I _E = 0 f = 1MHz	_	3	6	pF
Input resistor	RN1601	R1	_		3.29	4.7	6.11	- kΩ
	RN1602		_		7	10	13	
	RN1603		_		15.4	22	28.6	
	RN1604		_		32.9	47	61.1	
	RN1605		_		1.54	2.2	2.86	
	RN1606		_		3.29	4.7	6.11	
Resistor ratio	RN1601~1605	R1/R2	_	_	0.9	1.0	1.1	_
	RN1605		_		0.0421	0.0468	0.0515	
	RN1606		_		0.09	0.1	0.11	

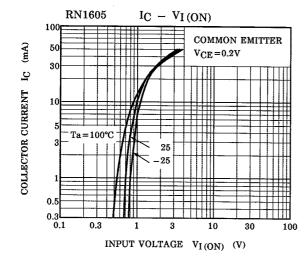
(Q1 Q2 Common)

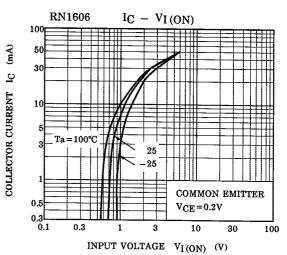






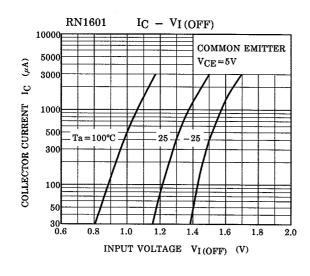


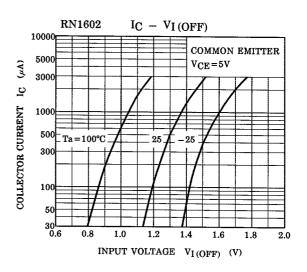


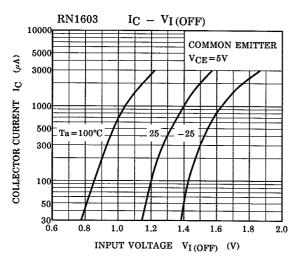


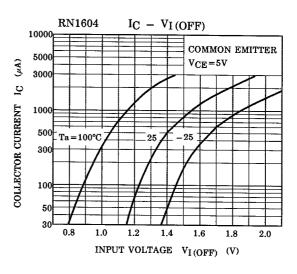
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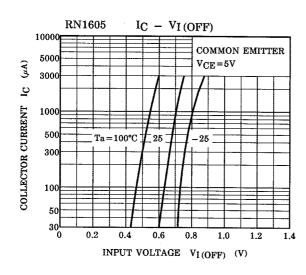
(Q1, Q2 Common)

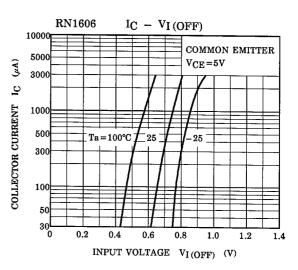




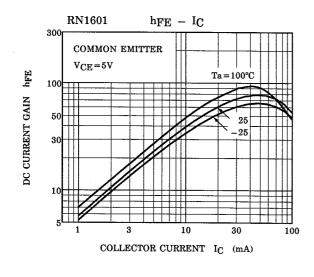


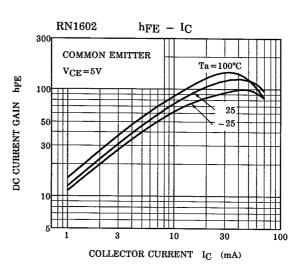


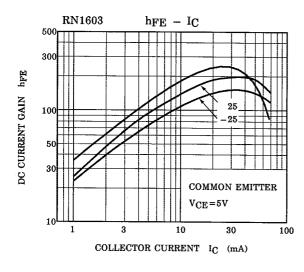


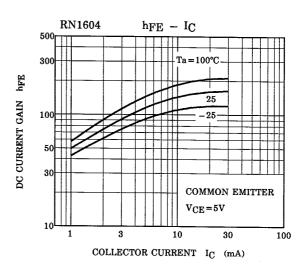


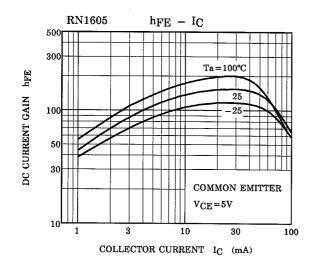
(Q1, Q2 Common)

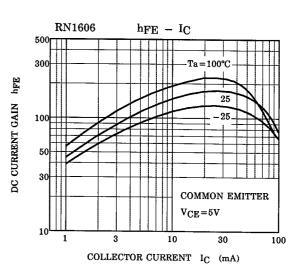












Type Name	Marking
RN1601	Type Name X A
RN1602	Type Name X B
RN1603	Type Name X C
RN1604	Type Name X D
RN1605	Type Name X E
RN1606	Type Name X F

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